



MC74VHC573, MC74VHCT573A

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
MC74VHC				
V_{CC}	DC Supply Voltage			

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DC ELECTRICAL CHARACTERISTICS (MC74VHC573)

Symbol	Parameter	Test Conditions	V _{CC} V	T _A = 25°C			T _A = - 40 to 85°C		Unit
				Min	Typ	Max	Min	Max	
V _{IH}	Minimum High-Level Input Voltage		2.0 3.0 to 5.5	1.50 V _{CC} x 0.7			1.50 V _{CC} x 0.7		V
V _{IL}	Maximum Low-Level Input Voltage		2.0 3.0 to 5.5			0.50 V _{CC} x 0.3		0.50 V _{CC} x 0.3	V
V _{OH}	Minimum High-Level Output Voltage	V _{in} = V _{IH} or V _{IL} I _{OH} = - 50 μA	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5		1.9 2.9 4.4		V
		V _{in} = V _{IH} or V _{IL} I _{OH} = - 4 mA I _{OH} = - 8 mA	3.0 4.5	2.58 3.94			2.48 3.80		
V _{OL}	Maximum Low-Level Output Voltage	V _{in} = V _{IH} or V _{IL} I _{OL} = 50 μA	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1	V
		V _{in} = V _{IH} or V _{IL} I _{OL} = 4m A I _{OL} = 8 mA	3.0 4.5			0.36 0.36		0.44 0.44	
I _{in}	Maximum Input Leakage Current	V _{in} = 5.5 V or GND	0 to 5.5			±0.1		±1.0	μA
I _{oz}	Maximum Three-State Leakage Current	V _{in} = V _{IL} or V _{IH} V _{out} = V _{CC} or GND	5.5			±0.25		±2.5	μA
I _{CC}	Maximum Quiescent Supply Current	V _{in} = V _{CC} or GND	5.5			4.0		40.0	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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AC ELECTRICAL CHARACTERISTICS (MC74VHC573)

Symbol	Parameter	Test Conditions	T _A = 25°C			T _A = - 40 to 85°C		Unit
			Min	Typ	Max	Min	Max	
t _{PLH} , t _{PHL}	Maximum Propagation Delay, LE to Q	V _{CC} = 3.3 ± 0.3 V C _L = 15 pF C _L = 50 pF		7.6 10.1	11.9 15.4	1.0 1.0	14.0 17.5	ns
		V _{CC} = 5.0 ± 0.5 V C _L = 15 pF C _L = 50 pF		5.0 6.5	7.7 9.7	1.0 1.0	9.0 11.0	
t _{PLH} , t _{PHL}	Maximum Propagation Delay, D to Q	V _{CC} = 3.3 ± 0.3 V C _L = 15 pF C _L = 50 pF		7.0 9.5	11.0 14.5	1.0 1.0	13.0 16.5	ns
		V _{CC} = 5.0 ± 0.5 V C _L = 15 pF C _L = 50 pF		4.5 6.0	6.8 8.8	1.0 1.0	8.0 10.0	
t _{PZL} , t _{PZH}	Output Enable Time, OE to Q	V _{CC} = 3.3 ± 0.3 V C _L = 15 pF C _L = 50 pF		7.3 9.8	11.5 15.0	1.0 1.0	13.5 17.0	ns
		V _{CC} = 5.0 ± 0.5 V C _L = 15 pF C _L = 50 pF		5.2 6.7	7.7 9.7	1.0 1.0	9.0 11.0	
t _{PLZ} , t _{PHZ}	Output Disable Time, OE to Q	V _{CC} = 3.3 ± 0.3 V C _L = 50 pF		10.7	14.5	1.0	16.5	ns
		V _{CC} = 5.0 ± 0.5 V C _L = 50 pF		6.7	9.7	1.0	11.0	
t _{OSLH} , t _{OSHL}	Output to Output Skew	V _{CC} = 3.3 ± 0.3 V C _L = 50 pF (Note 6)			1.5		1.5	ns
		V _{CC} = 5.5 ± 0.5 V C _L = 50 pF (Note 6)			1.0		1.0	ns
C _{in}	Maximum Input Capacitance			4	10		10	pF
C _{out}	Maximum Three-State Output Capacitance (Output in High-Im- pedance State)			6				pF

C _{PD}	Power Dissipation Capacitance (Note 7)	Typical @ 25°C, V _{CC} = 5.0 V		pF
		29		

6. Parameter guaranteed by design. t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|.

7. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}/8 (per latch). C_{PD} is used to determine the no-load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

NOISE CHARACTERISTICS (MC74VHC573) (C_L = 50 pF, V_{CC} = 5.0 V)

Symbol	Parameter	T _A = 25°C		Unit
		Typ	Max	
V _{OLP}	Quiet1 TD(722.3(p))JET408.756 268.044 .907 refq344.183 445.436sumptioCC)Tj8 0 0 8 244.48 08 740709 15.307e (Note 77543 297.865 30			

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DC ELECTRICAL CHARACTERISTICS (MC74VHCT573A)

Symbol	Parameter	Test Conditions	V _{CC} V	T _A = 25°C			T _A = - 40 to 85°C	Unit
				Min	Typ	Max		

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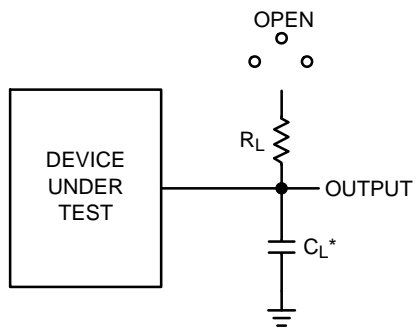
NOISE CHARACTERISTICS (MC74VHCT573A) ($C_L = 50 \text{ pF}$, $V_{CC} = 5.0 \text{ V}$)

Symbol	Parameter	$T_A = 25^\circ\text{C}$		Unit
		Typ	Max	
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	1.2	1.6	V
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	-1.2	-1.6	V
V_{IHD}	Minimum High Level Dynamic Input Voltage		2.0	V
V_{ILD}	Maximum Low Level Dynamic Input Voltage		0.8	V

TIMING REQUIREMENTS (MC74VHCT573A)

Symbol	Parameter	Test Conditions	$T_A = 25^\circ\text{C}$		$T_A = -40 \text{ to } 85^\circ\text{C}$	Unit
			Typ	Limit	Limit	
$t_{w(h)}$	Minimum Pulse Width, LE	$V_{CC} = 5.0 \pm 0.5\text{V}$		6.5	8.5	ns
t_{su}	Minimum Setup Time, D to LE	$V_{CC} = 5.0 \pm 0.5\text{V}$		1.5	1.5	ns
t_h	Minimum Hold Time, D to LE	$V_{CC} = 5.0 \pm 0.5\text{V}$		3.5	3.5	ns

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* C_L Includes probe and jig capacitance
Input signal $t_R = t_F = 3$ ns

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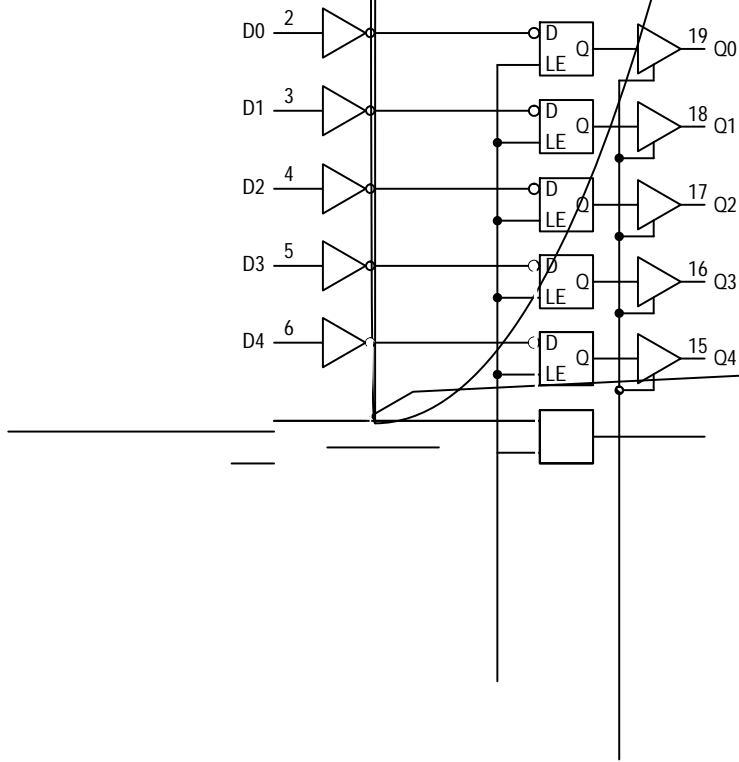
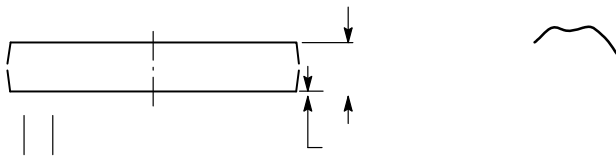
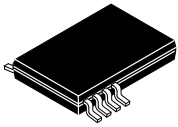


Figure 5. Expanded Logic Diagram

SOIC-20 WB
CASE 751D-05
ISSUE H

DATE 22 APR 2015





SCALE 2:1

TSSOP-20 WB
CASE 948E
ISSUE D

DATE 17 FEB 2016

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